## NSN 5962-00-497-0063

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Demilitarization: Yes - demil/mli



View Online at https://aerobasegroup.com/nsn/5962-00-497-0063

Body Length:	
0.896 inches	
Body Width:	
Between 0.220 inches and	0.310 inches
Body Height:	
Between 0.140 inches and	0.185 inches
Maximum Power Dissipa	tion Rating:
625.0 milliwatts	
Operating Tempurature I	lange:
55.0/+125.0 degrees cels	us
Storage Tempurature Ra	nge:
65.0/+150.0 degrees cels	us
Features Provided:	
Hermetically sealed and m	onolithic and positive outputs and w/enable and programmable and programmed and bipolar and w/buffered
output and w/decoded out	out and expandable and wire-or outputs
nclosure Material:	
Ceramic and glass	
nclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
nput Circuit Pattern:	
6 input	
Case Outline Source And	Designator:
D-2 mil-m-38510	
Terminal Surface Treatm	ent:
Solder	
Voltage Rating And Type	Per Characteristic:
5.5 volts power source	
Time Rating Per Chacter	stic:
50.00 nanoseconds propa	gation delay time, low to high level output
Memory Device Type:	
Rom	
Test Data Document:	
19956-461442 drawing (th	s is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc
excludes any specification	standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quar	tity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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**Fiig:** A458a0

